

## **8K Microwire Compatible Serial EEPROM**

#### **Device Selection Table**

Part Number	Vcc Range	ORG Pin	Pin PE Pin Word Size		Temp Ranges	Packages
93AA76A	1.8-5.5	No	No	8-bit	I	ОТ
93AA76B	1.8-5-5	No	No	16-bit	I	ОТ
93LC76A	2.5-5.5	No	No	8-bit	I, E	ОТ
93LC76B	2.5-5.5	No	No	16-bit	I, E	OT
93C76A	4.5-5.5	No	No	8-bit	I, E	ОТ
93C76B	4.5-5.5	No	No	16-bit	I, E	OT
93AA76C	1.8-5.5	Yes	Yes	8 or 16-bit	I	P, SN, ST, MS, MC
93LC76C	2.5-5.5	Yes	Yes	8 or 16-bit	I, E	P, SN, ST, MS, MC
93C76C	4.5-5.5	Yes	Yes	8 or 16-bit	I, E	P, SN, ST, MS, MC

#### Features:

- Low-power CMOS technology
- ORG pin to select word size for '76C' version
- 1024 x 8-bit organization 'A' devices (no ORG)
- 512 x 16-bit organization 'B' devices (no ORG)
- Program Enable pin to write-protect the entire array ('76C' version only)
- Self-timed erase/write cycles (including auto-erase)
- Automatic ERAL before WRAL
- Power-on/off data protection circuitry
- Industry standard 3-wire serial I/O
- Device Status signal (Ready/Busy)
- · Sequential read function
- 1,000,000 E/W cycles
- Data retention > 200 years
- Pb-free and RoHS compliant
- Temperature ranges supported:
  - Industrial (I) -40°C to +85°C
  - Automotive (E) -40°C to +125°C

#### **Pin Function Table**

Name	Function						
CS	Chip Select						
CLK Serial Data Clock							
DI	Serial Data Input						
DO	Serial Data Output						
Vss	Ground						
PE	Program Enable						
ORG	Memory Configuration						
Vcc	Power Supply						

#### **Description:**

The Microchip Technology Inc. 93XX76A/B/C devices are 8K bit, low-voltage, serial Electrically Erasable PROMs (EEPROM). Word-selectable devices such as the 93XX76C are dependent upon external logic levels driving the ORG pin to set word size. In the SOT-23 package, the 93XX76A devices provide dedicated 8-bit memory organization, while the 93XX76B devices provide dedicated 16-bit memory organization. A Program Enable (PE) pin allows the user to write-protect the entire memory array. Advanced CMOS technology makes these devices ideal for low-power, nonvolatile memory applications. The 93XX Series is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, 6-lead SOT-23, 8-lead 2x3 DFN and 8-lead TSSOP. All packages are Pb-free and RoHS compliant.

#### Package Types (not to scale)

		/				
	/SOIC SN)	SOT-23 (OT)				
CS [] CLK [2 DI [3 DO [4	8 Vcc 7 PE 6 ORG 5 Vss	DOC1 VssC2 DIC3	6 <u>-</u> ъ Vcc 5 -ъ CS 4 -ъ СLК			
	P/MSOP ; MS)	DFI (MC				
CS ☞ 1○ CLK ☞ 2 DI ☞ 3 DO ☞ 4	8चVcc 7चPE 6चORG 5चVss	CS 1• CLK 2 DI 3 DO 4	8 Vcc 7 PE 6 ORG 5 Vss			

## 1.0 ELECTRICAL CHARACTERISTICS

#### Absolute Maximum Ratings (†)

Vcc	7.0V
All inputs and outputs w.r.t. Vss	
Storage temperature	65°C to +150°C
Ambient temperature with power applied	40°C to +125°C
ESD protection on all pins	≥4 kV

**†** NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

#### TABLE 1-1: DC CHARACTERISTICS

		ply over the specified nerwise noted.	Industrial ( Automotive			C, VCC = +1.8V to 5.5V C, VCC = +2.5V to 5.5V			
Param. No.	Symbol	Parameter	Min	Тур	Мах	Units	Conditions		
D1	ViH1 ViH2	High-level input voltage	2.0 0.7 Vcc	_	Vcc +1 Vcc +1	V V	Vcc ≥ 2.7V Vcc < 2.7V		
D2	Vi∟1 Vi∟2	Low-level input voltage	-0.3 -0.3	_	0.8 0.2 Vcc	V V	Vcc ≥ 2.7V Vcc < 2.7V		
D3	Vol1 Vol2	Low-level output voltage		_	0.4 0.2	V V	IOL = 2.1 mA, VCC = 4.5V IOL = 100 μA, VCC = 2.5V		
D4	Vон1 Vон2	High-level output voltage	2.4 Vcc - 0.2	_	_	V V	ІОН = -400 μA, Vcc = 4.5V ІОН = -100 μA, Vcc = 2.5V		
D5	ILI	Input leakage current	_	—	±1	μA	VIN = VSS or VCC		
D6	Ilo	Output leakage current	_	—	±1	μA	VOUT = VSS or VCC		
D7	CIN, COUT	Pin capacitance (all inputs/ outputs)	—	—	7	pF	VIN/VOUT = 0V <b>(Note 1)</b> TA = 25°C, FCLK = 1 MHz		
D8	ICC write	Write current		 500	3	mA μA	FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 2.5V		
D9	ICC read	Read current		 100	1 500 —	mA μA μA	FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 3.0V FCLK = 2 MHz, VCC = 2.5V		
D10	Iccs	Standby current	—	_	1 5	μΑ μΑ	I – Temp E – Temp CLK = CS = 0V ORG = DI = PE = Vss or Vcc (Note 2) (Note 3)		
D11	VPOR	Vcc voltage detect		1.5 3.8	_	V V	(Note 1) 93AA76A/B/C, 93LC76A/B/C 93C76A/B/C		

Note 1: This parameter is periodically sampled and not 100% tested.

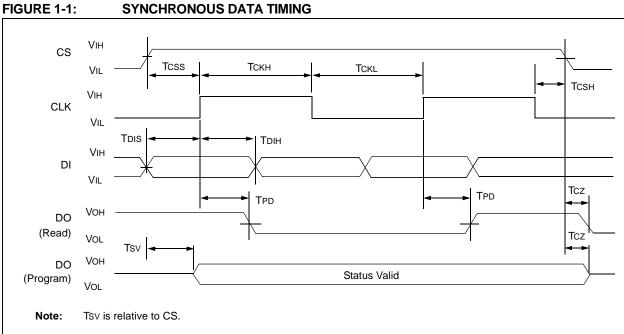
2: ORG and PE pins not available on 'A' or 'B' versions.

3: Ready/Busy status must be cleared from DO, see Section 3.4 "Data Out (DO)".

		ply over the specified nerwise noted.	Industrial Automotiv			to +85°C, Vcc = +1.8V to 5.5V to +125°C, Vcc = +2.5V to 5.5V
Param. No.	Symbol	Parameter	Min	Мах	Units	Conditions
A1	FCLK	Clock frequency	_	3 2 1	MHz MHz MHz	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A2	Тскн	Clock high time	200 250 450	_	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A3	TCKL	Clock low time	100 200 450	_	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A4	Tcss	Chip Select setup time	50 100 250	_	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A5	Тсѕн	Chip Select hold time	0	_	ns	1.8V ≤ Vcc < 5.5V
A6	TCSL	Chip Select low time	250	_	ns	1.8V ≤ VCC < 5.5V
A7	TDIS	Data input setup time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A8	Тоін	Data input hold time	50 100 250		ns ns ns	$4.5V \le VCC < 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$
A9	TPD	Data output delay time	_	100 250 400	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF
A10	Tcz	Data output disable time	-	100 200	ns ns	4.5V ≤ VCC < 5.5V, (Note 1) 1.8V ≤ VCC < 4.5V, (Note 1)
A11	Ts∨	Status valid time	-	200 300 500	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF
A12	Twc	Program cycle time	-	5	ms	Erase/Write mode (AA and LC versions)
A13	Twc		_	2	ms	Erase/Write mode (93C versions)
A14	TEC	]		6	ms	ERAL mode, $4.5V \le VCC \le 5.5V$
A15	TWL			15	ms	WRAL mode, $4.5V \le VCC \le 5.5V$
A16	_	Endurance	1M	_	cycles	25°C, Vcc = 5.0V, (Note 2)

Note 1: This parameter is periodically sampled and not 100% tested.

2: This application is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance<sup>™</sup> Model which may be obtained from Microchip's web site at www.microchip.com.



#### TABLE 1-3: INSTRUCTION SET FOR X 16 ORGANIZATION (93XX76B OR 93XX76C WITH ORG = 1)

Instruction	SB	Opcode					Add	ress					Data In	Data Out	Req. CLK Cycles
READ	1	10	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0		D15-D0	29
EWEN	1	00	1	1	х	x	x	х	х	х	х	x	—	High-Z	13
ERASE	1	11	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0	_	(RDY/BSY)	13
ERAL	1	00	1	0	Х	Х	Х	Х	Х	Х	Х	Х	_	(RDY/BSY)	13
WRITE	1	01	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0	D15-D0	(RDY/BSY)	29
WRAL	1	00	0	1	x	x	х	х	x	х	x	х	D15-D0	(RDY/BSY)	29
EWDS	1	00	0	0	х	х	х	х	х	х	х	х	_	High-Z	13

Instruction	SB	Opcode		Address					Data In	Data Out	Req. CLK Cycles					
READ	1	10	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	—	D7-D0	22
EWEN	1	00	1	1	x	х	х	х	х	х	х	x	х	—	High-Z	14
ERASE	1	11	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	—	(RDY/BSY)	14
ERAL	1	00	1	0	x	x	х	х	x	x	х	x	х	—	(RDY/BSY)	14
WRITE	1	01	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	D7-D0	(RDY/BSY)	22
WRAL	1	00	0	1	x	x	х	х	х	x	х	x	х	D7-D0	(RDY/BSY)	22
EWDS	1	00	0	0	x	x	x	х	x	x	х	x	x	_	High-Z	14

### 2.0 FUNCTIONAL DESCRIPTION

When the ORG pin (93XX76C) is connected to Vcc, the (x16) organization is selected. When it is connected to ground, the (x8) organization is selected. Instructions, addresses and write data are clocked into the DI pin on the rising edge of the clock (CLK). The DO pin is normally held in a High-Z state except when reading data from the device, or when checking the Ready/Busy status during a programming operation. The Ready/Busy status can be verified during an Erase/Write operation by polling the DO pin; DO low indicates that programming is still in progress, while DO high indicates the device is ready. DO will enter the High-Z state on the falling edge of CS.

#### 2.1 Start Condition

The Start bit is detected by the device if CS and DI are both high with respect to the positive edge of CLK for the first time.

Before a Start condition is detected, CS, CLK and DI may change in any combination (except to that of a Start condition), without resulting in any device operation (Read, Write, Erase, EWEN, EWDS, ERAL or WRAL). As soon as CS is high, the device is no longer in Standby mode.

An instruction following a Start condition will only be executed if the required opcode, address and data bits for any particular instruction are clocked in.

Note:	When preparing to transmit an instruction,
	either the CLK or DI signal levels must be
	at a logic low as CS is toggled active high.

#### 2.2 Data In/Data Out (DI/DO)

It is possible to connect the Data In and Data Out pins together. However, with this configuration it is possible for a "bus conflict" to occur during the "dummy zero" that precedes the read operation, if A0 is a logic highlevel. Under such a condition the voltage level seen at Data Out is undefined and will depend upon the relative impedances of Data Out and the signal source driving A0. The higher the current sourcing capability of the driver, the higher the voltage at the Data Out pin. In order to limit this current, a resistor should be connected between DI and DO.

#### 2.3 Data Protection

All modes of operation are inhibited when Vcc is below a typical voltage of 1.5V for '93AA' and '93LC' devices or 3.8V for '93C' devices.

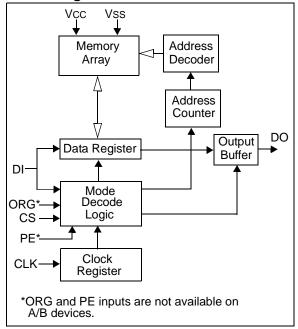
The EWEN and EWDS commands give additional protection against accidentally programming during normal operation.

Note:	For	added	prot	tectic	on,	an	Е	WDS				
	comr	nand sł	nould	be	per	forme	ed	after				
	every write operation and an external 10											
	kΩ p	ull-down	proted	ction	resis	stor sl	hou	uld be				
	adde	d to the (	CS pir	า.								

After power-up the device is automatically in the EWDS mode. Therefore, an EWEN instruction must be performed before the initial ERASE or WRITE instruction can be executed.

Note: To prevent accidental writes to the array in the 93XX76C devices, set the PE pin to a logic low.

#### **Block Diagram**



#### 2.4 Erase

The ERASE instruction forces all data bits of the specified address to the logical '1' state. The rising edge of CLK before the last address bit initiates the write cycle.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been erased and the device is ready for another instruction.

**Note:** After the Erase cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

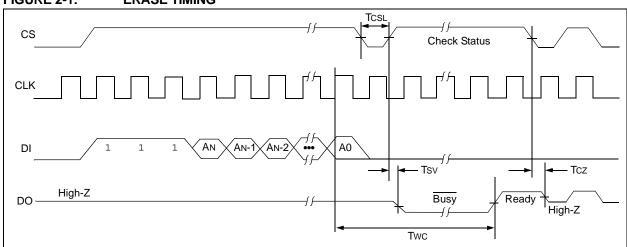


FIGURE 2-1: ERASE TIMING

### 2.5 Erase All (ERAL)

The Erase All (ERAL) instruction will erase the entire memory array to the logical '1' state. The ERAL cycle is identical to the erase cycle, except for the different opcode. The ERAL cycle is completely self-timed. The rising edge of CLK before the last data bit initiates the write cycle. Clocking of the CLK pin is not necessary after the device has entered the ERAL cycle.

The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL).

Note: After the ERAL command is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

VCC must be  $\geq$  4.5V for proper operation of ERAL.

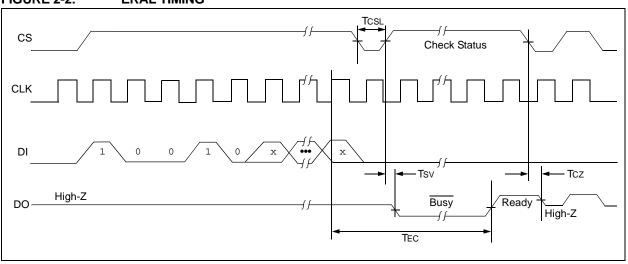


FIGURE 2-2: ERAL TIMING

## 2.6 Erase/Write Disable and Enable (EWDS/EWEN)

The 93XX76A/B/C powers up in the Erase/Write Disable (EWDS) state. All programming modes must be preceded by an Erase/Write Enable (EWEN) instruction.

Once the EWEN instruction is executed, programming remains enabled until an EWDS instruction is executed or Vcc is removed from the device.

To protect against accidental data disturbance, the EWDS instruction can be used to disable all erase/write functions and should follow all programming operations. Execution of a READ instruction is independent of both the EWEN and EWDS instructions.

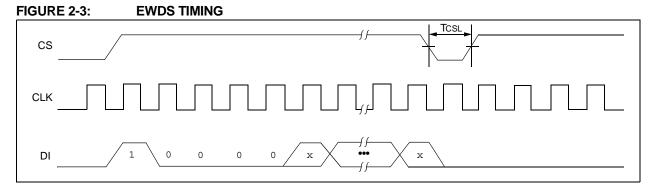
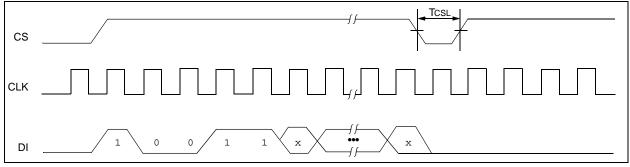


FIGURE 2-4: EW

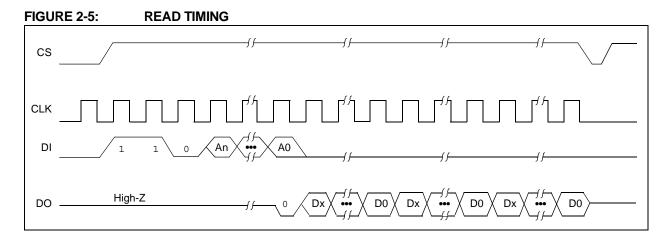
EWEN TIMING



#### 2.7 Read

The READ instruction outputs the serial data of the addressed memory location on the DO pin. A dummy zero bit precedes the 8-bit (If ORG pin is low or A-Version devices) or 16-bit (If ORG pin is high or B-version devices) output string.

The output data bits will toggle on the rising edge of the CLK and are stable after the specified time delay (TPD). Sequential read is possible when CS is held high. The memory data will automatically cycle to the next register and output sequentially.

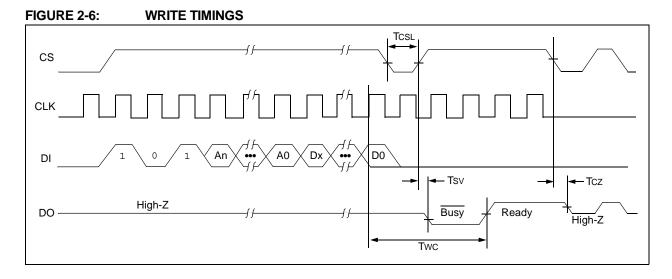


#### 2.8 Write

The WRITE instruction is followed by 8 bits (if ORG is low or A-version devices) or 16 bits (if ORG pin is high or B-version devices) of data which are written into the specified address. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been written with the data specified and the device is ready for another instruction.

Note: The write sequence requires a logic high signal on the PE pin prior to the rising edge of the last data bit.

Note: After the Write cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.



#### 2.9 Write All (WRAL)

The Write All (WRAL) instruction will write the entire memory array with the data specified in the command. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. Clocking of the CLK pin is not necessary after the device has entered the WRAL cycle. The WRAL command does include an automatic ERAL cycle for the device. Therefore, the WRAL instruction does not require an ERAL instruction, but the chip must be in the EWEN status.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL) ..

Note:	The write sequence requires a logic high									
	signal on the PE pin prior to the rising									
	edge of the last data bit.									

Note:	After the Write All cycle is complete,
	issuing a Start bit and then taking CS low
	will clear the Ready/Busy status from DO.

Vcc must be  $\geq$  4.5V for proper operation of WRAL.

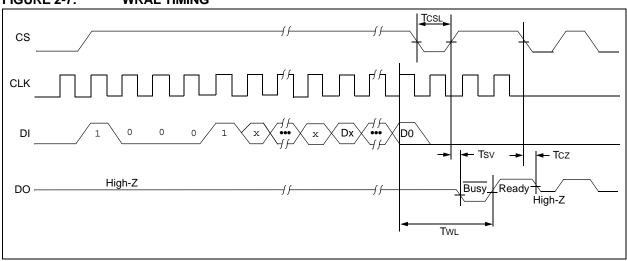


FIGURE 2-7: WRAL TIMING

### 3.0 PIN DESCRIPTIONS

#### TABLE 3-1:PIN DESCRIPTIONS

Name	SOIC/PDIP/MSOP/ TSSOP/DFN	SOT-23	Function
CS	1	5	Chip Select
CLK	2	4	Serial Clock
DI	3	3	Data In
DO	4	1	Data Out
Vss	5	2	Ground
ORG	6	—	Organization / 93XX76C
PE	7	_	Program Enable
Vcc	8	6	Power Supply

#### 3.1 Chip Select (CS)

A high level selects the device; a low level deselects the device and forces it into Standby mode. However, a programming cycle which is already in progress will be completed, regardless of the Chip Select (CS) input signal. If CS is brought low during a program cycle, the device will go into Standby mode as soon as the programming cycle is completed.

CS must be low for 250 ns minimum (TCSL) between consecutive instructions. If CS is low, the internal control logic is held in a Reset status.

### 3.2 Serial Clock (CLK)

The Serial Clock is used to synchronize the communication between a master device and the 93XX series device. Opcodes, address and data bits are clocked in on the positive edge of CLK. Data bits are also clocked out on the positive edge of CLK.

CLK can be stopped anywhere in the transmission sequence (at high or low-level) and can be continued anytime with respect to Clock High Time (TCKH) and Clock Low Time (TCKL). This gives the controlling master freedom in preparing opcode, address and data.

CLK is a "don't care" if CS is low (device deselected). If CS is high, but the Start condition has not been detected (DI = 0), any number of clock cycles can be received by the device without changing its status (i.e., waiting for a Start condition).

CLK cycles are not required during the self-timed write (i.e., auto erase/write) cycle.

After detection of a Start condition the specified number of clock cycles (respectively, low-to-high transitions of CLK) must be provided. These clock cycles are required to clock in all required opcode, address and data bits before an instruction is executed. CLK and DI then become "don't care" inputs waiting for a new Start condition to be detected.

### 3.3 Data In (DI)

Data In (DI) is used to clock in a Start bit, opcode, address and data synchronously with the CLK input.

### 3.4 Data Out (DO)

Data Out (DO) is used in the Read mode to output data synchronously with the CLK input (TPD after the positive edge of CLK).

This pin also provides Ready/Busy status information during erase and write cycles. Ready/Busy status information is available on the DO pin if CS is brought high after being low for minimum Chip Select Low Time (TCsL) and an erase or write operation has been initiated.

The Status signal is not available on DO, if CS is held low during the entire erase or write cycle. In this case, DO is in the High-Z mode. If status is checked after the erase/write cycle, the data line will be high to indicate the device is ready.

Note: After a programming cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

### 3.5 Organization (ORG)

When the ORG pin is connected to VCC or Logic HI, the (x16) memory organization is selected. When the ORG pin is tied to VSS or Logic LO, the (x8) memory organization is selected. For proper operation, ORG must be tied to a valid logic level.

93XX76A devices are always x8 organization and 93XX76B devices are always x16 organization.

### 3.6 Program Enable (PE)

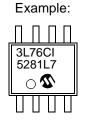
This pin allows the user to enable or disable the ability to write data to the memory array. If the PE pin is tied to Vcc, the device can be programmed. If the PE pin is tied to Vss, programming will be inhibited. This pin cannot be floated, it must be tied to Vcc or Vss. PE is not available on 93XX76A or 93XX76B. On those devices, programming is always enabled.

#### 4.0 **PACKAGING INFORMATION**

#### 4.1 **Package Marking Information**

8-Lead MSOP (150 mil)





Example: ппп

4EL7

Example: <u>п п п п</u>

93LC76C

I/P (e3) 1L7

**1**0528

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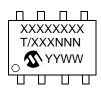
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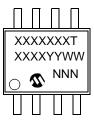
6-Lead SOT-23

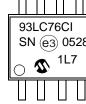


8-Lead PDIP



8-Lead SOIC





8-Lead TSSOP
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8-Lead 2x3 DFN

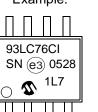




L7

SOT23 Marking Codes							
Device I-temp E-temp							
93AA76A	_						
93AA76B	4LNN	_					
93LC76A 4ENN 4FNN							
93LC76B	4PNN	4RNN					
93C76A	4HNN	4JNN					
93C76B 4TNN 4UNN							
Pb-free topside mark is same; Pb-free noted only on carton label.							

Example:



Example:

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г

L76C

1528

1L7

	1st Line Marking Codes						
Part Number	TSSOP	MSOP	DFN				
	1330P	WISOP	l Temp.	E Temp.			
93AA76C	A76C	3A76CT	3B1				
93LC76C	L76C	3L76CT	3B4	3B5			
93C76C	C76C	3C76CT	3B7	3B8			

**Note:** T = Temperature grade (I, E)

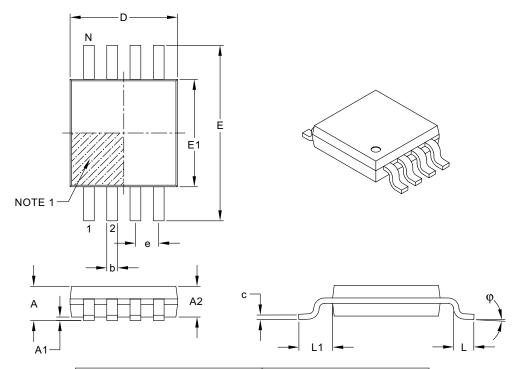
Legend	: XXX T Y YY WW NNN @3	Part number or part number code Temperature (I, E) Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code (2 characters for small packages) Pb-free JEDEC designator for Matte Tin (Sn)
Note:		small packages with no room for the Pb-free JEDEC designator marking will only appear on the outer carton or reel label.
Note:	be carrie	ent the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

Note: Please visit www.microchip.com/Pbfree for the latest information on Pb-free conversion.

\*Standard OTP marking consists of Microchip part number, year code, week code, and traceability code.

#### 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	MIN	NOM	MAX		
Number of Pins	Ν		8		
Pitch	е		0.65 BSC		
Overall Height	Α	—	—	1.10	
Molded Package Thickness	A2	0.75	0.85	0.95	
Standoff	A1	0.00	—	0.15	
Overall Width	E	4.90 BSC			
Molded Package Width	E1	3.00 BSC			
Overall Length	D	3.00 BSC			
Foot Length	L	0.40	0.60	0.80	
Footprint			0.95 REF		
Foot Angle	φ	0°	—	8°	
Lead Thickness	С	0.08	—	0.23	
Lead Width	b	0.22	—	0.40	

#### Notes:

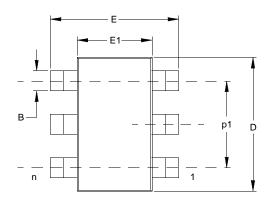
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M

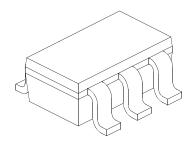
BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

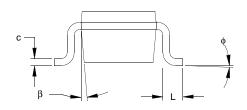
Microchip Technology Drawing No. C04–111, Sept. 8, 2006

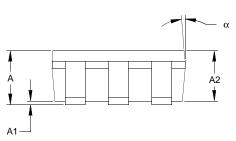
#### 6-Lead Plastic Small Outline Transistor (OT) (SOT-23)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging









	Units	INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		6			6	
Pitch	р		038 BSC		(	).95 BSC	
Outside lead pitch	p1		075 BSC			1.90 BSC	
Overall Height	А	.035	.046	.057	0.90	1.18	1.45
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30
Standoff	A1	.000	.003	.006	0.00	0.08	0.15
Overall Width	E	.102	.110	.118	2.60	2.80	3.00
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75
Overall Length	D	.110	.116	.122	2.80	2.95	3.10
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	¢	0	5	10	0	5	10
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.014	.017	.020	0.35	0.43	0.50
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. BSC: Basic Dimension. Theoretically exact value shown without tolerances.

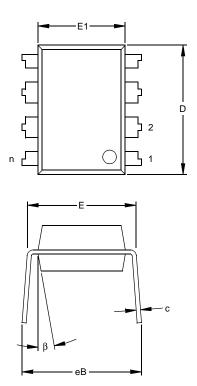
See ASME Y14.5M

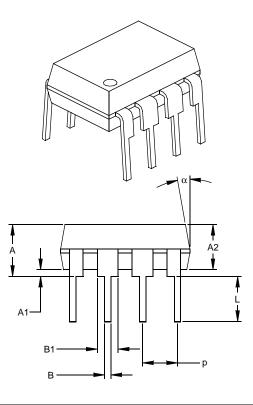
JEITA (formerly EIAJ) equivalent: SC-74A Drawing No. C04-120

Revised 09-12-05

#### 8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





	Units	INCHES*			MILLIMETERS		
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	А	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

\* Controlling Parameter

§ Significant Characteristic

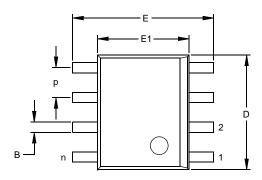
Notes:

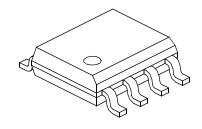
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001

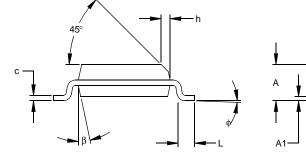
Drawing No. C04-018

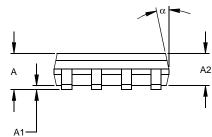
#### 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging









	Units		INCHES*			MILLIMETERS		
Dimensi	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		8			8		
Pitch	р		.050			1.27		
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75	
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55	
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25	
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20	
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99	
Overall Length	D	.189	.193	.197	4.80	4.90	5.00	
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51	
Foot Length	L	.019	.025	.030	0.48	0.62	0.76	
Foot Angle	φ	0	4	8	0	4	8	
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25	
Lead Width	В	.013	.017	.020	0.33	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	
* Osatasllina Dansasstan	Р	0	12	10	0	12	1.	

\* Controlling Parameter § Significant Characteristic

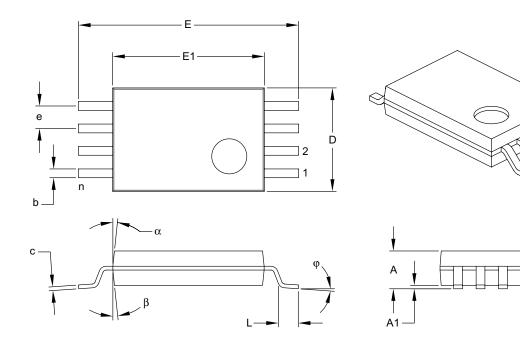
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-057

#### 8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	INCHES			MILLIMETERS*			
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	е		.026 BSC			0.65 BSC	
Overall Height	Α	-	_	.047	_	_	1.20
Molded Package Thickness	A2	.031	.039	.041	0.80	1.00	1.05
Standoff	A1	.002	_	.006	0.05	_	0.15
Overall Width	E		.252 BSC		6.40 BSC		
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.114	.118	.122	2.90	3.00	3.10
Foot Length	L	.018	.024	.030	0.45	0.60	0.75
Foot Angle	φ	0°	_	8°	0°	_	8°
Lead Thickness	С	.004	_	.008	0.09	_	0.20
Lead Width	b	.007	_	.012	0.19	-	0.30
Mold Draft Angle Top	α	12° REF		12° REF			
Mold Draft Angle Bottom	β		12° REF			12° REF	

\*Controlling Parameter

#### Notes:

1. Dimension D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

See ASME Y14.5M

REF: Reference Dimension, usually without tolerance, for information purposes only.

See ASME Y14.5M

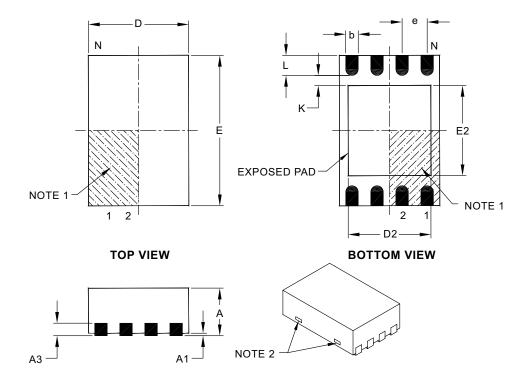
Drawing No. C04-086

Revised 7-25-06

A2 -

#### 8-Lead Plastic Dual Flat No Lead Package (MC) 2x3x0.9 mm Body (DFN) – Saw Singulated

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	Ν		8		
Pitch	е		0.50 BSC		
Overall Height	Α	0.80	0.90	1.00	
Standoff	A1	0.00	0.00 0.02		
Contact Thickness	A3		0.20 REF		
Overall Length	D		2.00 BSC		
Overall Width	E		3.00 BSC		
Exposed Pad Length	D2	1.30	—	1.75	
Exposed Pad Width	E2	1.50	—	1.90	
Contact Width	b	0.18	0.25	0.30	
Contact Length §	L	0.30	0.40	0.50	
Contact-to-Exposed Pad §	K	0.20	_	—	

#### Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. § Significant Characteristic
- 4. Package is saw singulated
- 5. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-123, Sept. 8, 2006

### APPENDIX A: REVISION HISTORY

#### **Revision C**

Corrections to Section 1.0, Electrical Characteristics. Section 4.1, 6-Lead SOT-23 package to OT.

#### **Revision D**

Corrections to Device Selection Table, Table 1-1, Table 1-2, Section 2.4, Section 2.5, Section 2.8 and Section 2.9. Added note to Figure 2-7.

#### **Revision E**

Added DFN package.

#### **Revision F**

Added notes throughout.

#### **Revision G**

Revised note in Sections 2.8 and 2.9. Replaced DFN package drawing.

#### **Revision H**

Updated Package Drawings

NOTES:

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PART NO.	¥	×	<u>/xx</u>	<u>×</u>		Exa	mples:
Device Ta	ipe & Reel	 Temperature Range	Package	Lead F	inish	a)	93AA76C-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, 1.8V
		Runge				b)	93AA76AT-I/OT: 8K, 1024x8 Serial EEPROM, SOT-23 package, tape and reel, 1.8V
Device:	93AA76	A: 8K 1.8V Micro B: 8K 1.8V Micro C: 8K 1.8V Micro	wire Serial EE	EPROM (x1	16)	c)	93AA76CT-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, tape and reel, 1.8V
		A: 8K 2.5V Micro				a)	93LC76C-I/MS: 8K, 1024x8 or 512x16 Serial
		B: 8K 2.5V Micro C: 8K 2.5V Micro				b)	EEPROM, MSOP package, 2.5V 93LC76BT-I/OT: 8K, 512x16 Serial EEPROM, SOT-23 package, tape and reel, 2.5V
	93C76A 93C76B						
	93C76C					a)	93C76C-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, 5.0V
						b)	93C76AT-I/OT: 8K, 1024x8 Serial EEPROM, SOT-23 package, tape and reel, 5.0V
Tape & Reel:	Blank = T =						
Temperature Range	e:   = E =						
Package:	MS = OT = P = SN =	SOT-23, 6-le Plastic DIP	0P (Micro Sma ead (Tape & R (300 mil body) C (150 mil bod	Reel only) ), 8-lead	8-lead)		
		TSSOP, 8-le 2x3 DFN, 8-					
Lead Finish:	Blank =		atte Tin <b>(see I</b>	Note 1)			
	G =	Pb-free – M	atte Tin only				

Note 1: Most products manufactured after January 2005 will have a Matte Tin (Pb-free) finish. Most products manufactured before January 2005 will have a finish of approximately 63% Sn and 37% Pb (Sn/Pb).

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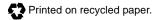
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